ELEG 340: Solid-State Electronics, Fall 2008

Homework #9 (rev) - due Tuesday, 18 November 2008, at the beginning of class

- 1. Problem 7.7, p. 392 of Streetman-Banerjee, 6th edition. Hint: use the Ebers-Moll equations in form of Eqn. (7-34) and used the distribution most like that of a simple p-n junction diode. The idea is to find the Δp_E and Δp_C that are most like those of an ideal pn diode.
- 2. Problem 7.10 (without drawing the current arrows), p. 393 of Streetman-Banerjee, 6th edition. Note: do not show the current arrows and directions; just calculate the parameters.
- 3. Problem 7.11, p. 393 of Streetman-Banerjee, 6^{th} edition. How much does the base width narrow compared to the equilibrium value? Hint: this is called the Early effect, after James Early. Note that $V_{CB} = -50 \text{ V}$ using our sign convention.
- 4. Problem 7.18 ($V_{EB} = 0.2 \text{ V}$ only), p. 394 of Streetman-Banerjee, 6^{th} edition. This problem emphasizes the difference between metallurgical base width W_{met} (or L_b as on p. 371 or text), and neutral base width W_B . Hint: since the emitter doping >> base doping, assume that the depletion width W_{BE} extends only into the base, so that the base portion of W_{BE} = its full value. Note calculate only for $V_{EB} = 0.2 \text{ V}$; do not repeat the calculation for $V_{EB} = 0.6 \text{ V}$
- 5. Problem 7.24, p. 395 of Streetman-Banerjee, 6th edition. Only calculate the emitter base bias; do not comment on the injection efficiency.

Homework assignments will appear on the web at: http://www.ece.udel.edu/~kolodzey/courses/eleg340f08.html

Note: On each homework and report submission, please give your name, the due date, assignment number and the course number.